

## **NCE N-Channel Super Trench Power MOSFET**

#### **Description**

The NCEP02580F uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{\text{DS(ON)}}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

#### **General Features**

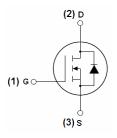
- $V_{DS} = 250V, I_D = 80A$  $R_{DS(ON)} < 18.5 m\Omega @ V_{GS} = 10V$
- Excellent gate charge x R<sub>DS(on)</sub> product
- Very low on-resistance R<sub>DS(on)</sub>
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

### **Application**

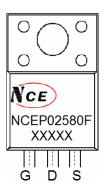
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

100% UIS TESTED!

100% ΔVds TESTED!



#### Schematic diagram



Marking and pin assignment



TO-220F top view

#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP02580F	NCEP02580F	TO-220F-3L	-	-	-

Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	250	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	80	Α
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	56.6	Α
Pulsed Drain Current	I <sub>DM</sub>	320	Α
Maximum Power Dissipation	P <sub>D</sub>	50	W
Derating factor		3	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	1200	mJ
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 175	$^{\circ}$



# **Thermal Characteristic**

Thermal Resistance,Junction-to-Case <sup>(Note 2)</sup>	$R_{ heta JC}$	0.33	°C/W	
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Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	·					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	250		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =250V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2.5		4.5	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =40A	-	16	18.5	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =10V,I <sub>D</sub> =40A	70	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	.,	-	5400	-	PF
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =125V, $V_{GS}$ =0V, F=1.0MHz	-	329	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	r=1.0WIn2	-	12	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	18	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =125 $V$ , $I_D$ =40 $A$	-	26	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{G}$ =4.7 $\Omega$	-	41	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	11	-	nS
Total Gate Charge	Qg	\/ 405\/\ 400	-	76.7		nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =125V,I <sub>D</sub> =40A,	-	22.7		nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	20		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	$V_{SD}$	V <sub>GS</sub> =0V,I <sub>S</sub> =80A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	80	Α
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25^{\circ}C$ , $I_F = 40$	-	140		nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	600		nC

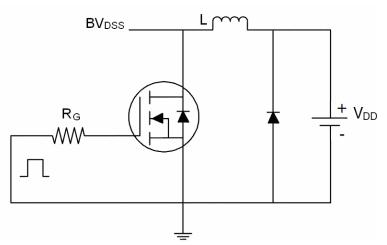
### Notes:

- ${\it 1. Repetitive Rating: Pulse width limited by maximum junction temperature.}\\$
- 2. Surface Mounted on FR4 Board, t  $\leq$  10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^{\circ}$ C,V<sub>DD</sub>=50V,V<sub>G</sub>=10V,L=0.5mH,Rg=25 $\Omega$

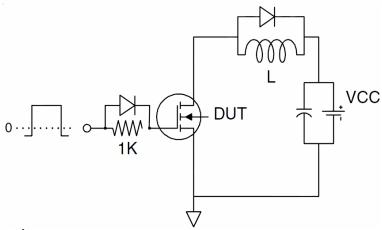


### **Test Circuit**

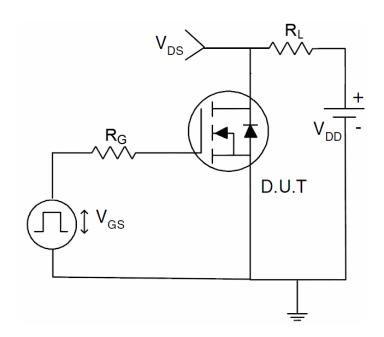
# 1) E<sub>AS</sub> test Circuit



# 2) Gate charge test Circuit

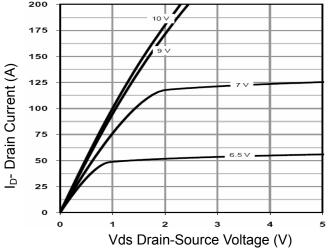


# 3) Switch Time Test Circuit

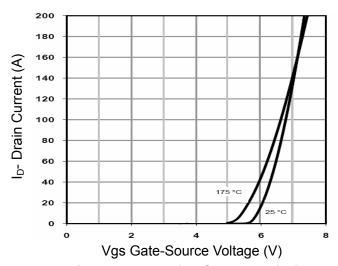








**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

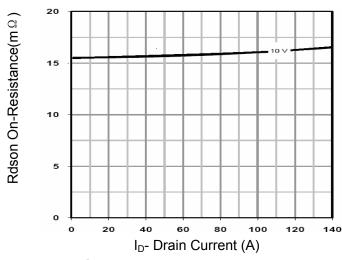


Figure 3 Rdson- Drain Current

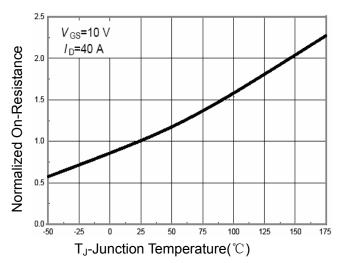


Figure 4 Rdson-JunctionTemperature

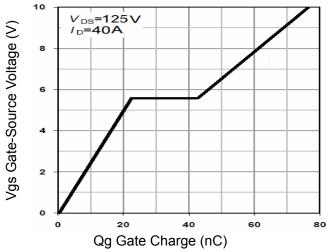


Figure 5 Gate Charge

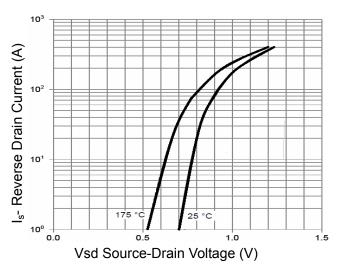
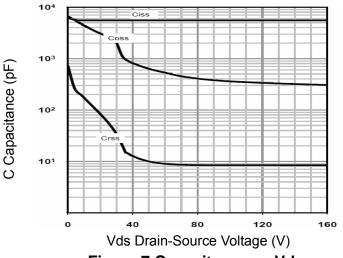


Figure 6 Source- Drain Diode Forward





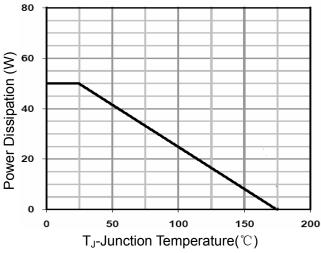
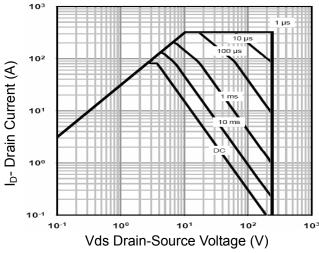
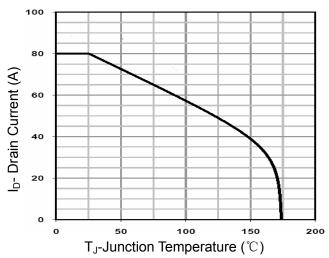


Figure 7 Capacitance vs Vds

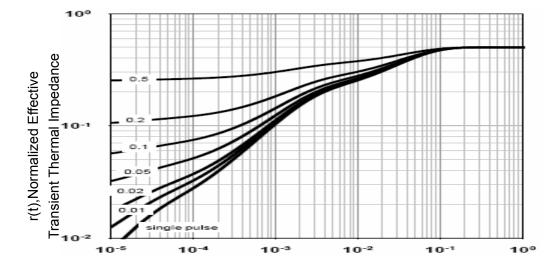
Figure 9 Power De-rating





**Figure 8 Safe Operation Area** 

Figure 10 Current De-rating

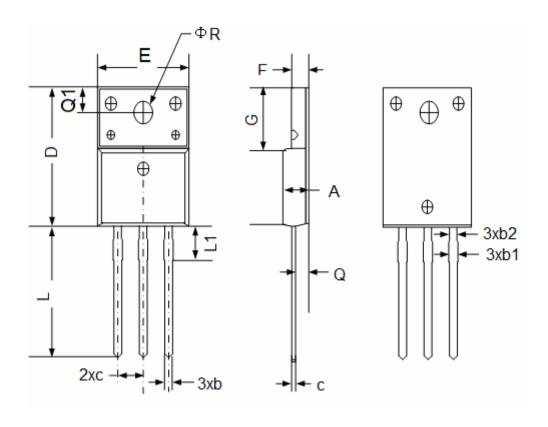


Square Wave Pluse Duration(sec)

**Figure 11 Normalized Maximum Transient Thermal Impedance** 



# **TO-220F Package Information**



Symbol	Dimensions	In Millimeters	Dimensions In Inches			
	Min.	Max.	Min.	Max.		
А	4.50	4.83	0. 18	0. 19		
b	0.70	0.91	0.03	0.04		
b1	1.20	1.47	0.05	0.06		
b2	1.10	1.38	0.04	0.05		
С	0.45	0.63	0. 02	0.02		
D	15.67	16.07	0. 62	0.63		
е	2.54	BSC	0.10 BSC			
Е	9.96	10.36	0. 39	0.41		
F	2.34	2.74	0.09	0. 11		
G	6.48	6.90	0. 26	0. 27		
L	12.68	13.30	0. 50	0. 52		
L1	3.13	3.50	0. 12	0.14		
Q	2.56	2.93	0. 10	0. 12		
Q1	3.20	3.40	0. 13	0. 13		
ΦR	3.08	3.28	0. 12	0. 13		



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